PMBT3904MB
40 V, 200 mA NPN switching transistor
Rev. 1 - 7 March 2012
Product data sheet

## 1. Product profile

### 1.1 General description

NPN single switching transistor in a leadless ultra small SOT883B Surface-Mounted Device (SMD) plastic package.

PNP complement: PMBT3906MB.

### 1.2 Features and benefits

- Single general-purpose switching transistor
- AEC-Q101 qualified
- Ultra small SMD plastic package
- Board-space reduction
- Low package height of 0.37 mm


### 1.3 Applications

- General-purpose switching and amplification
- Mobile applications


### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{V}_{\text {CEO }}$ | collector-emitter voltage | open base | - | - | 40 | V |
| $\mathrm{I}_{\mathrm{C}}$ | collector current |  | - | - | 200 | mA |
| $\mathrm{~h}_{\text {FE }}$ | DC current gain | $\mathrm{V}_{\text {CE }}=1 \mathrm{~V} ;$ <br> $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}$ | 100 | 180 | 300 |  |

## 2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
| :---: | :---: | :---: | :---: |
| 1 | base |  |  |
| 2 | emitter | $1$ | 3 |
| 3 | collector | $2$ |  |
|  |  | Transparent top view | $2$ |
|  |  |  | sym021 |



## 3. Ordering information

Table 3. Ordering information

| Type number | Package |  |  |
| :--- | :--- | :--- | :--- |
|  | Name | Description | Version |
| PMBT3904MB |  | leadless ultra small plastic package; 3 solder lands; <br> body $1.0 \times 0.6 \times 0.37 \mathrm{~mm}$ | SOT883B |

4. Marking

Table 4. Marking codes

| Type number | Marking code ${ }^{[1]}$ |
| :--- | :--- |
| PMBT3904MB | 01000111 |

[1] For SOT883B binary marking code description see Figure 1.

### 4.1 Binary marking code description



## 5. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{V}_{\text {CBO }}$ | collector-base voltage | open emitter | - | 60 | V |
| $\mathrm{~V}_{\mathrm{CEO}}$ | collector-emitter voltage | open base | - | 40 | V |
| $\mathrm{~V}_{\text {EBO }}$ | emitter-base voltage | open collector | - | 6 | V |
| $\mathrm{I}_{\mathrm{C}}$ | collector current |  | - | 200 | mA |
| $\mathrm{I}_{\mathrm{CM}}$ | peak collector current | single pulse; <br> $\mathrm{t}_{\mathrm{p}} \leq 1 \mathrm{~ms}$ | - | 200 | mA |
| $\mathrm{I}_{\mathrm{BM}}$ | peak base current | single pulse; <br> $\mathrm{t}_{\mathrm{p}} \leq 1 \mathrm{~ms}$ | - | 100 | mA |
| $\mathrm{P}_{\text {tot }}$ | total power dissipation | $\mathrm{T}_{\text {amb }} \leq 25^{\circ} \mathrm{C}$ | $\underline{[1][2]}-$ | 250 | mW |
|  |  |  | $\underline{[1][3]}-$ | 590 | mW |
| $\mathrm{~T}_{\mathrm{j}}$ | junction temperature |  | - | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {amb }}$ | ambient temperature |  | -55 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |

[1] Reflow soldering is the only recommended soldering method.
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector $1 \mathrm{~cm}^{2}$.

## 6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{R}_{\mathrm{th}(\mathrm{j}-\mathrm{a})}$ | thermal resistance from <br> junction to ambient | in free air | $\underline{[1][2]}-$ | - | 500 | K/W |
|  |  | $\underline{[1][3]}-$ | - | 212 | K/W |  |

[1] Reflow soldering is the only recommended soldering method.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector $1 \mathrm{~cm}^{2}$.


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 7. Characteristics

Table 7. Characteristics
$T_{\text {amb }}=25^{\circ} \mathrm{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {cbo }}$ | collector-base cut-off current | $\mathrm{V}_{C B}=30 \mathrm{~V} ; \mathrm{I}_{\mathrm{E}}=0 \mathrm{~A}$ | - | - | 50 | nA |
| $\mathrm{I}_{\text {ebo }}$ | emitter-base cut-off current | $\mathrm{V}_{\mathrm{EB}}=6 \mathrm{~V} ; \mathrm{I}_{\mathrm{C}}=0 \mathrm{~A}$ | - | - | 50 | nA |
| $h_{\text {FE }}$ | DC current gain | $\mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}$ |  |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=0.1 \mathrm{~mA}$ | 60 | 180 | - |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ | 80 | 180 | - |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}$ | 100 | 180 | 300 |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA}$ | 60 | 105 | - |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA}$ | [1] 30 | 50 | - |  |
| $\mathrm{V}_{\text {CEsat }}$ | collector-emitter saturation voltage | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} ; \mathrm{I}_{\mathrm{B}}=1 \mathrm{~mA}$ | - | 75 | 200 | mV |
|  |  | $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA} ; \mathrm{I}_{\mathrm{B}}=5 \mathrm{~mA}$ | - | 120 | 300 | mV |
| $V_{\text {BEsat }}$ | base-emitter saturation voltage | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}$; $\mathrm{I}_{\mathrm{B}}=1 \mathrm{~mA}$ | 650 | 750 | 850 | mV |
|  |  | $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA} ; \mathrm{I}_{\mathrm{B}}=5 \mathrm{~mA}$ | - | 850 | 950 | mV |
| $\mathrm{t}_{\mathrm{d}}$ | delay time | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V} ; \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} ; \\ & \mathrm{I}_{\text {Bon }}=1 \mathrm{~mA} ; \\ & \mathrm{I}_{\text {Boff }}=-1 \mathrm{~mA} \end{aligned}$ | - | - | 35 | ns |
| $\mathrm{tr}_{r}$ | rise time |  | - | - | 35 | ns |
| $\mathrm{t}_{\text {on }}$ | turn-on time |  | - | - | 70 | ns |
| $\mathrm{t}_{\text {s }}$ | storage time |  | - | - | 200 | ns |
| $t_{f}$ | fall time |  | - | - | 50 | ns |
| $\mathrm{t}_{\text {off }}$ | turn-off time |  | - | - | 250 | ns |
| $\mathrm{C}_{\mathrm{c}}$ | collector capacitance | $\begin{aligned} & V_{C B}=5 \mathrm{~V} ; \mathrm{I}_{\mathrm{E}}=\mathrm{i}_{\mathrm{e}}=0 \mathrm{~A} ; \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | - | 4 | pF |
| $\mathrm{C}_{\text {e }}$ | emitter capacitance | $\begin{aligned} & \mathrm{V}_{\mathrm{EB}}=500 \mathrm{mV} ; \\ & \mathrm{I}_{\mathrm{C}}=\mathrm{i}_{\mathrm{C}}=0 \mathrm{~A} ; \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | - | 8 | pF |
| $\mathrm{f}_{T}$ | transition frequency | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=20 \mathrm{~V} ; \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} ; \\ & \mathrm{f}=100 \mathrm{MHz} \end{aligned}$ | 300 | - | - | MHz |
| NF | noise figure | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V} ; \mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A} ; \\ & \mathrm{R}_{\mathrm{S}}=1 \mathrm{k} ; \\ & \mathrm{f}=10 \mathrm{~Hz} \text { to } 15.7 \mathrm{kHz} \end{aligned}$ | - | - | 5 | dB |

[1] Pulse test: $\mathrm{t}_{\mathrm{p}} \leq 300 \mu \mathrm{~s} ; \delta \leq 0.02$.


$$
V_{C E}=1 \mathrm{~V}
$$

(1) $\mathrm{T}_{\mathrm{amb}}=150^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$
(3) $\mathrm{T}_{\mathrm{amb}}=-55^{\circ} \mathrm{C}$

Fig 3. DC current gain as a function of collector current; typical values

$\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$

Fig 4. Collector current as a function of collector-emitter voltage; typical values

$\mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}$
(1) $\mathrm{T}_{\mathrm{amb}}=-55^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$
(3) $\mathrm{T}_{\mathrm{amb}}=150^{\circ} \mathrm{C}$

Fig 5. Base-emitter voltage as a function of collector current; typical values

$\mathrm{I}_{\mathrm{C}} / \mathrm{I}_{\mathrm{B}}=10$
(1) $\mathrm{T}_{\mathrm{amb}}=-55^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$
(3) $\mathrm{T}_{\mathrm{amb}}=150^{\circ} \mathrm{C}$

Fig 6. Base-emitter saturation voltage as a function of collector current; typical values

$I_{C} I_{B}=10$
(1) $\mathrm{T}_{\mathrm{amb}}=150^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$
(3) $\mathrm{T}_{\mathrm{amb}}=-55^{\circ} \mathrm{C}$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values
8. Test information


Fig 8. Test circuit for switching times

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

## 9. Package outline



Fig 9. Package outline SOT883B

## 10. Packing information

Table 8. Packing methods
The indicated -xxx are the last three digits of the 12NC ordering code. [1]

| Type number | Package | Description |
| :--- | :--- | :--- |
| PMBT3904MB SOT883B | 2 mm pitch, 8 mm tape and reel | $\mathbf{1 0 0 0 0}$ |

[1] For further information and the availability of packing methods, see Section 14.

## 11. Soldering



Reflow soldering is the only recommended soldering method.
Fig 10. Reflow soldering footprint SOT883B

40 V, 200 mA NPN switching transistor

## 12. Revision history

Table 9. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| :--- | :--- | :--- | :--- | :--- | :--- |
| PMBT3904MB v.1 | 20120307 | Product data sheet | - | - |

## 13. Legal information

### 13.1 Data sheet status

| Document status $[1][2]$ | Product status $[3]$ | Definition |
| :--- | :--- | :--- |
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